An Efficient 1-D Periodic Boundary Integral Equation Technique to Analyze Radiation onto Straight and Meandering Microstrip Lines

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Abstract—A modeling technique to analyze the radiation onto arbitrary 1-D periodic metallizations residing on a microstrip substrate is presented. In particular, straight and meandering lines are being studied. The method is based on a boundary integral equation (BIE), more specifically on a mixed potential integral equation (MPIE), that is solved by means of the Method of Moments (MoM). A plane wave excites the microstrip structure, and according to the Floquet-Bloch theorem, the analysis can be restricted to one single unit cell. Therewith, the MPIE must be constructed using the pertinent 1-D periodic layered medium Green’s functions. Here, these Green’s functions are obtained in closed form by invoking the Perfectly Matched Layer (PML)-paradigm. The proposed method is applied to assess the radiation onto (i) a semi-infinite plate, (ii) a straight microstrip line, and (iii) a serpentine delay line. These three types of examples clearly illustrate and validate the method. Also, its efficiency, compared to a previously developed fast microstrip analysis technique, is demonstrated.

Index Terms—Green’s function, periodic structure, Perfectly Matched Layer, electromagnetic radiation, integral equation, Method of Moments, microstrip structure, meandering lines

I. INTRODUCTION

Frequency selective surfaces [1], [2], metamaterials [3], electromagnetic bandgap and defected ground structures [4], [5], leaky wave antennas [6], antenna arrays [7], and wire-medium screens [8] are some typical examples of structures that can exhibit a one-dimensional (1-D), a two-dimensional (2-D), or a three-dimensional (3-D) periodicity. Also, a 1-D periodic meandering character of interconnect structures can be exploited (or introduced) to make them stretchable [9] or to use them as delay lines [10]. Often, techniques to analyze the electromagnetic properties of periodic structures with an infinite extent are based on the Floquet-Bloch theorem, allowing to consider one single representative unit cell. When constructing boundary integral equation (BIE) techniques, the pertinent periodic Green’s function of the background medium under consideration needs to be computed in order to determine the unknown fields or current distributions within this unit cell. Upon knowledge of the Green’s function, the BIE can be solved by the Method of Moments (MoM) [11]. An overview of techniques is provided in [12]. Additionally, a new interesting method based on fast periodic interpolations is reported in [13].

Many structures reside in a layered dielectric background medium. Hence, layered medium periodic Green’s functions and BIE-MoM based solution schemes leveraging these Green’s functions are of particular interest. Unfortunately, cumbersome Sommerfeld-type integrals then have to be dealt with, leading to a time-consuming numerical evaluation of the layered medium Green’s functions. The evaluation of the Sommerfeld-integrals is a challenging research topic. In [14] an efficient sum of inverse Fourier transforms is constructed to tackle the Sommerfeld-integrals. In [15] a novel application of the Perfectly Matched Layer (PML) has been presented. Whereas the PML was originally conceived to serve as an absorbing boundary condition to terminate the simulation domain in finite element and finite difference based full-wave solvers, in [15] the PML is used to construct closed-form expressions of layered medium Green’s functions. Apart from a rapid evaluation of the pertinent Green’s functions, these closed-from expressions can also be used, for example, to construct Fast Multipole Methods [16]–[18]. In [19] the PML-paradigm was applied to conceive 3-D layered medium 1-D periodic Green’s functions. As the PML-based periodic Green’s functions can be constructed in an elegant and natural way, it is very beneficial to implement them within a BIE-MoM scheme. This technique has been successfully applied in [12] to analyze the scattering and radiation from/by 1-D periodic microstrip antenna arrays. However, the technique presented in [12] can only be applied to antenna arrays as a completely arbitrary shape of the metallization within one unit cell was not allowed. In contrast, the method presented in this paper allows to rapidly evaluate the current density on arbitrary 1-D periodic microstrip metallizations, illuminated by a plane wave. In particular, lines with a 1-D periodicity, such as serpentine delay lines [10], are considered. The analysis of such structures is of specific importance to assess possible electromagnetic interference (EMI) issues.

This paper is organized as follows. In Section II the formalism is presented. The PML-paradigm and the periodic Green’s functions resulting from it are briefly revisited and the implementation of the PML-based Green’s functions in a BIE-MoM scheme is presented. Special attention is devoted to the construction of the MoM in order to allow a continuous current flow across the unit cell’s borders. The formalism is validated and illustrated in Section III by considering the radiation onto (i) a large, semi-infinite, perfect electrically conducting (PEC) plate, (ii) a straight microstrip line, and (iii) a serpentine delay line. Conclusions are summarized in Section IV.

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In the sequel, all sources and fields are assumed to be time-harmonic with angular frequency \(\omega\) and time dependencies \(e^{j\omega t}\) are suppressed. Also, transverse to \(z\) restrictions of vectors \(\mathbf{v}\) are denoted \(\mathbf{v} = v_x \hat{x} + v_y \hat{y} = -\hat{z} \times [\hat{x} \times \mathbf{v}]\); here \(\hat{x}, \hat{y}, \hat{z}\) are unit Cartesian vectors.

II. DESCRIPTION OF THE TECHNIQUE

A. Geometry

![Image of a 1-D periodic microstrip structure](image)

Fig. 1: A 1-D periodic microstrip structure, i.e., a meandering line, illuminated by a plane wave \(\mathbf{E}^{PW}\).

Consider the microstrip geometry of Fig. 1. It consists of a substrate of thickness \(d\), relative permittivity \(\varepsilon_r\), and relative permeability \(\mu_r\), that resides on a perfect electrically conducting (PEC) ground plate. At the substrate-air interface \(z = d\), a PEC metallization \(\mathcal{M}\) is placed. This metallization exhibits a 1-D periodicity with period \(b\) along the \(x\)-direction. The \(m\)th unit cell is denoted \(S_{uc,m} = \{\mathbf{r} = x\hat{x} + y\hat{y} + dz : mb \leq x < (m+1)b, -\infty < y < \infty\}, m \in \mathbb{Z}\). In contrast to our previous work [12], which only allowed the analysis of antenna arrays, here the metallization extends across the borders of the unit cells, allowing a continuous current flow in the \(x\)-direction. A plane wave \(\mathbf{E}^{PW}(r) = E_0 e^{-j(k_0 r)}\) illuminates the structure. Here, \(k_0 = \omega/c\) is the free-space wavenumber, with \(c = 1/\sqrt{\varepsilon_0 \mu_0}\) the speed of light in vacuum. The unit vector \(\mathbf{k} = -\sin \theta \cos \phi \hat{x} - \sin \theta \sin \phi \hat{y} - \cos \theta \hat{z}\) determines the plane wave’s spherical angles of incidence \(\theta\) and \(\phi\).

B. 1-D periodic BIE-MoM Formalism

Due to the plane wave, an incident field \(\mathbf{E}^i(r)\) is present, which induces an unknown current density \(\mathbf{J}(\rho)\) on the metallization. In turn, a scattered field \(\mathbf{E}^s(r)\) is produced. A BIE, and more specifically a mixed potential integral equation (MPIE), is now constructed by demanding that the total tangential electric field, i.e., \(\mathbf{E}^t(r) = \mathbf{E}^i(r) + \mathbf{E}^s(r)\), vanishes at the metallization \(\mathcal{M}_{uc,m} = \mathcal{M} \cap S_{uc,m}\) that resides within the \(m\)th unit cell:

\[
\mathbf{E}^t(\rho) = \frac{j\omega}{2} \int_{\mathcal{M}_{uc,m}} \mathbf{G}^\text{dep}_V(\rho | \rho') \mathbf{J}(\rho') d\rho' - \frac{1}{j\omega} \nabla \int_{\mathcal{M}_{uc,m}} \mathbf{G}^\text{dep}_A(\rho | \rho')(\nabla \cdot \mathbf{J}(\rho')) d\rho',
\]

\(\forall \rho \in \mathcal{M}_{uc,m}\),

(1)

with \(\nabla = \frac{\partial}{\partial x} \hat{x} + \frac{\partial}{\partial y} \hat{y}\). The pertinent 1-D periodic Green’s functions \(\mathbf{G}^\text{dep}_A(\rho | \rho')\) and \(\mathbf{G}^\text{dep}_V(\rho | \rho')\) will be discussed later (see Section II-C). The MPIE (1) is solved by the MoM. Thereto, the metallization is approximated by a rectilinear mesh, as indicated in Fig. 2 (where the depicted metallization \(\mathcal{M}_{uc,m}\) is chosen to be a rectangle of length \(b\) and width \(w\)). The unknown current density \(\mathbf{J}(\rho)\) is expanded into a set of \(x\)- and \(y\)-oriented vector rooftop basis functions. In this example, the metallization \(\mathcal{M}_{uc,m}\) is a rectangle of length \(b\) and width \(w\).

![Image of discretization](image)

Fig. 2: Discretization of the metallization within the \(m\)th unit cell into a rectilinear mesh and some corresponding vector rooftop basis functions. In this example, the metallization \(\mathcal{M}_{uc,m}\) is a rectangle of length \(b\) and width \(w\).

1) the edge is an \(x\)-oriented edge (e.g., edge \(j\) in Fig. 2);
2) the edge is a \(y\)-oriented edge that does not reside on the borders \(x = nb\) or \(x = (m+1)b\) of the unit cell (e.g., edge \(k\) in Fig. 2);
3) the edge is a \(y\)-oriented edge that resides on the border \(x = (m+1)b\) of the unit cell (e.g., edge \(l\) in Fig. 2).

In this case, it is noticed that, within this unit cell, the support \(M^-\) for the falling part of the vector rooftop function does not reside next to the support \(M^+\).

Edges residing on the border \(x = nb\) have to be neglected, i.e., no basis function should be introduced for these edges, as otherwise the matrix system (see further) would become overdetermined. This is because it is required that the current density is periodic, apart from a phase difference \(\psi\), as follows:

\[
\mathbf{J}(\rho + b\hat{x}) = \mathbf{J}(\rho) e^{j\psi},
\]

(2)

with

\[
\psi = -b k_0 \sin \theta \cos \phi.
\]

(3)

The property (2) is a direct consequence of the Floquet-Bloch theorem. To enforce this property, first, the support \(M^-\) of the rooftop basis functions corresponding to edges that reside on the border \(x = (m+1)b\) consists of a first cell \(M^+\) that is adjacent to this border (rising flank of the function) and a second cell \(M^-\) that is adjacent to the border \(x = nb\) (falling flank of the function) (see Fig. 2). Next, assuming that there are \(N\) edges after discretization of the metallization, the unknown current density is expanded as follows:

\[
\mathbf{J}(\rho) = \sum_{j=1}^{N} I_j \mathbf{w}_j^\text{dep}(\rho).
\]

(4)
For edges that are not on the border \( x = (m + 1)b \), in the above expansion (4) the basis functions \( \mathbf{w}_{ij}^{\text{per}}(\rho) \) are the classic well-known rooftop basis functions. For edges that are on the border \( x = (m + 1)b \), the falling flank of the rooftop function (e.g., with support \( M^- \) in Fig. 2) is subjected to a phase shift so that the requirement (2) is fulfilled. A similar procedure was applied in [21] to develop a 2-D hybrid finite-element (FE)/BIE solver for periodic absorbers. For completeness, note that this procedure can also be applied using Rao-Wilton-Glisson (RWG) basis functions, as described in [14]. Inserting (4) into the MPIE (1) and applying a Galerkin testing procedure [22] results in an \( N \times N \) linear system in the unknown expansion coefficients \( I_j, j = 1, \ldots, N \):

\[
\mathbf{V} = \mathbf{Z} \cdot \mathbf{I}.
\]

The \( N \)-vector \( \mathbf{V} \), with elements \( V_i, i = 1, \ldots, N \), and the \( N \times N \) matrix \( \mathbf{Z} \), with elements \( Z_{ij}, i = 1, \ldots, N, j = 1, \ldots, N \), are given by:

\[
V_i = \int \mathbf{E}^{\text{in}}(\rho) \cdot \mathbf{w}_{i}^{\text{per}}(\rho) \, d\rho,
\]

\[
Z_{ij} = j\omega \int \int_{M^+} \int_{M^-} G^{\text{per}}_A(\rho, \rho') \left( \mathbf{w}_{i}^{\text{per}}(\rho') \cdot \mathbf{w}_{j}^{\text{per}}(\rho') \right) \, d\rho' \, d\rho + \frac{1}{j\omega} \int \int_{M^+} \int_{M^-} G^{\text{per}}_V(\rho, \rho') \left( \nabla \cdot \mathbf{w}_{i}^{\text{per}}(\rho) \right) \times \left( \nabla' \cdot \mathbf{w}_{j}^{\text{per}}(\rho') \right) \, d\rho' \, d\rho.
\]

The linear system (5) can be solved by means of direct or iterative schemes.

### C. 1-D periodic Green’s functions

Upon knowledge of the 1-D periodic layered medium Green’s functions \( G^{\text{per}}_A(\rho, \rho') \) and \( G^{\text{per}}_V(\rho, \rho') \) for the magnetic vector potential and for the electric scalar potential respectively, the MoM system (5) is fully determined. Unfortunately, the computation of these Green’s functions is rather cumbersome and time-consuming when applying a classic procedure. As stated in [14], such a procedure involves an inverse Fourier Transform of a discrete sum of Floquet modes, as follows:

\[
G^{\text{per}}_{A, V}(\rho, \rho') = \sum_{m=-\infty}^{+\infty} e^{-j\xi(x-x')} \int G^{\text{per}}_{A, V}(\xi, k_y) e^{-jk_y(y-y')} \, dk_y,
\]

with

\[
\xi = \frac{\psi}{b} + 2\pi m \frac{b}{b}.
\]

This series (8) converts the well-known spectral Green’s functions \( G^{\text{per}}_A(\xi, k_y) \) and \( G^{\text{per}}_V(\xi, k_y) \) (see [23]) into spatial Green’s functions \( G^{\text{per}}_{A, V}(\rho, \rho') \) and \( G^{\text{per}}_{A, V}(\rho, \rho') \). No analytical expressions are available for (8). This is due to the presence of the semi-infinite layer of air \( z > d \) (Fig. 1). This layer corresponds to a continuous set of radiation modes in the modal spectrum of the microstrip substrate, necessitating the cumbersome, numerical evaluation of Sommerfeld-integrals [24–26]. Here, we adopt the PML-paradigm [15], which is detailed in [19] for 1-D periodic layered medium Green’s functions.

The semi-infinite layer of air above the microstrip substrate is terminated by a PEC plate placed at a complex distance \( z = d + \mathcal{D} \) (Fig. 3). It can be shown [15] that a proper choice of \( \mathcal{D} \) leads to a so-called PML-closed waveguide that very closely mimics the behavior of the original, open waveguide, as the original modal spectrum is now replaced by a discrete set of TE- and TM-polarized modes of the PML-closed substrate. Consequently, the Green’s functions of the PML-closed waveguide have the interesting property that they can be written as analytical sums of transverse electric (TE) and transverse magnetic (TM) PML-modes. As such, the following expressions for the pertinent spatial 3-D Greens functions for a 1-D periodic grid of point sources are obtained:

\[
G^{\text{per}}_{A, V}(\rho, \rho') = \frac{j}{2} \sum_{n=1}^{+\infty} \sum_{m=-\infty}^{+\infty} \frac{e^{-j\mu_0 \gamma \sqrt{\mu_0 \epsilon_0} (\rho, \rho') \rho_0} H^{(2)}_{\nu}(\beta_{TE,n} \Delta_m)}{M_{TE}(\beta_{TE,n})},
\]

\[
G^{\text{per}}_{V}(\rho, \rho') = \frac{j}{2} \sum_{n=1}^{+\infty} \sum_{m=-\infty}^{+\infty} \frac{e^{-j\mu_0 \gamma \sqrt{\mu_0 \epsilon_0} (\rho, \rho') \rho_0} H^{(2)}_{\nu}(\beta_{TM,n} \Delta_m)}{M_{TM}(\beta_{TM,n})},
\]

where \( \Delta_m = \sqrt{(x-x' - mb)^2 + (y-y')^2} \) and with

\[
M_{TE}(\beta) = \frac{d}{\mu_0 \epsilon_0 \mu_0 \gamma_0} \frac{1}{\gamma_1 d} + \frac{D}{\mu_0 \gamma_0} \frac{1}{\gamma_1 d} + \frac{\epsilon_0 \epsilon_0}{\gamma_0} \frac{1}{\gamma_1 d} + \frac{\epsilon_0 \epsilon_0 d}{\gamma_0} \frac{1}{\gamma_1 d} + \frac{\epsilon_0 \epsilon_0 d}{\gamma_0} \frac{1}{\gamma_1 d} + \frac{\epsilon_0 \epsilon_0 d}{\gamma_0} \frac{1}{\gamma_1 d} + \frac{\epsilon_0 \epsilon_0 d}{\gamma_0} \frac{1}{\gamma_1 d} + \frac{\epsilon_0 \epsilon_0 d}{\gamma_0} \frac{1}{\gamma_1 d},
\]

\[
M_{TM}(\beta) = \frac{1}{\mu_0 \epsilon_0 \mu_0 \gamma_0} \frac{1}{\gamma_1 d} + \frac{D}{\mu_0 \gamma_0} \frac{1}{\gamma_1 d} + \frac{\epsilon_0 \epsilon_0}{\gamma_0} \frac{1}{\gamma_1 d} + \frac{\epsilon_0 \epsilon_0 d}{\gamma_0} \frac{1}{\gamma_1 d} + \frac{\epsilon_0 \epsilon_0 d}{\gamma_0} \frac{1}{\gamma_1 d} + \frac{\epsilon_0 \epsilon_0 d}{\gamma_0} \frac{1}{\gamma_1 d} + \frac{\epsilon_0 \epsilon_0 d}{\gamma_0} \frac{1}{\gamma_1 d} + \frac{\epsilon_0 \epsilon_0 d}{\gamma_0} \frac{1}{\gamma_1 d} + \frac{\epsilon_0 \epsilon_0 d}{\gamma_0} \frac{1}{\gamma_1 d}.
\]

where \( \gamma_0 = \sqrt{k_0^2 - \beta^2} \) and \( \gamma_1 = \sqrt{k_0^2 \epsilon_\mu_0 - \beta^2} \). In (10) and (11), \( H^{(2)}_{\nu}(\cdot) \) is the zeroth-order Hankel function of the second kind. Although the summations over the modes \( n \) in (10) and (11) have an infinite extent, because of the fact that the modal propagation constants \( \beta_{TE,n} \) and \( \beta_{TM,n} \) are located in the fourth quadrant of the complex plane, only a limited set of these modes needs to be retained. In all examples
presented below (Section III), less than 100 modes are used. It was explained in [16] that these modes come in three flavors, which exhibit different behavior. The choice of the PML-parameters, i.e., the choice of the complex thickness $D$, has to be appropriate to provide sufficient damping of the modal fields inside the PML for each of these modes. The influence of $D$ was also discussed in [27], along with an indicator of the quality of this choice. For large $n$, the series in (10) and (11) converge at a rate proportional to $e^{-n C_1 \Delta m}$, with $C_1$ a constant. Hence, given this exponential decay as a function of $n$ and provided that the distance $\Delta m$ is not too small, these are fast converging series. For small $n$ or for small distances $\Delta m$, however, a combination of techniques — such as Poisson summation, Shank’s acceleration, and/or Ewald splitting — has to be applied to improve the convergence. A rigorous description of these techniques is outside the scope of this work, but they are described in detail in [19] and the references therein. In summary, it has been shown that the PML-paradigm allows computing layered medium Green’s functions, and 1-D periodic layered medium Green’s functions in particular, in a very efficient and elegant way, this in contrast to more classical Sommerfeld-approaches. In this paper, for the first time, the PML-based approach is adopted to construct a 1-D periodic BIE-MoM for the analysis of straight and meandering microstrip lines.

III. NUMERICAL EXAMPLES

The 1-D periodic BIE-MoM technique is now validated and illustrated by considering representative (application) examples. First, the currents induced on a large semi-infinite PEC plate are studied, leading to a validation of the technique. Second, the radiation onto a straight microstrip line is modeled.

A. Semi-infinite plate

As a first example a large PEC plate is considered. The metallization within one unit cell $m = 0$ is shown in Fig. 2. It was explained in [16] that these modes come in three flavors, which exhibit different behavior. The choice of the PML-parameters, i.e., the choice of the complex thickness $D$, has to be appropriate to provide sufficient damping of the modal fields inside the PML for each of these modes. The influence of $D$ was also discussed in [27], along with an indicator of the quality of this choice. For large $n$, the series in (10) and (11) converge at a rate proportional to $e^{-n C_1 \Delta m}$, with $C_1$ a constant. Hence, given this exponential decay as a function of $n$ and provided that the distance $\Delta m$ is not too small, these are fast converging series. For small $n$ or for small distances $\Delta m$, however, a combination of techniques — such as Poisson summation, Shank’s acceleration, and/or Ewald splitting — has to be applied to improve the convergence. A rigorous description of these techniques is outside the scope of this work, but they are described in detail in [19] and the references therein. In summary, it has been shown that the PML-paradigm allows computing layered medium Green’s functions, and 1-D periodic layered medium Green’s functions in particular, in a very efficient and elegant way, this in contrast to more classical Sommerfeld-approaches. In this paper, for the first time, the PML-based approach is adopted to construct a 1-D periodic BIE-MoM for the analysis of straight and meandering microstrip lines.

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A. Semi-infinite plate

As a first example a large PEC plate is considered. The metallization within one unit cell $m = 0$ is shown in Fig. 2. With $b = 5$ mm and $w = 300$ mm. So, the length of the plate along the $y$-dimension is 10 free-space wavelengths $\lambda_0 = 2\pi/\omega_0$. The plate has an infinite extent along the $x$-axis. The metallization resides on a PEC-backed non-magnetic substrate of thickness $d = 3.17$ mm and with relative permittivity $\varepsilon_r = 11.7$. The PEC plate is illuminated by a plane wave $E_{PW}(r) = (x + iy)e^{j\omega_0 z}, i.e. under perpendicular incidence ($\theta = 0^\circ$), and with an angular frequency of $\omega = 2\pi 10$ GHz. The current density on this PEC plate, induced by the plane wave, is computed using the technique described in Section II. The magnitude and the phase of the $x$- and $y$-oriented current densities are shown in Figs. 4 and 5 respectively. In Fig. 6 the magnitude of the $x$- and the $y$-oriented current densities is shown along the cross-section $x = (m + 1/2)b = 2.5$ mm. The results are explained as follows. Given the perpendicular incidence of the plane wave, the situation can be considered as a pure 2-D situation, i.e. there is no variation along the $x$-dimension. In this case, Maxwell’s equations can be split into a TE- and a TM-part w.r.t. the $x$-axis. This was clearly described in [29], where the corresponding 2-D PEC plate was simulated. The results obtained here with the periodic BIE-MoM are exactly the same as those presented in [29]: (i) For the $x$-oriented current (corresponding to a 2-D TM-solution) the plane wave is completely reflected at the nearly infinitely large PEC plate. Hence, apart from some expected edge effects at $y = 0$ and $y = 10\lambda_0$, the magnitude of the induced currents equals twice the incident $x$-component of the magnetic field, i.e. $|J_x| = 2\sqrt{\frac{\omega_0}{\varepsilon_0}} \frac{\lambda_0}{m} = 5.3 \frac{\sqrt{\mu_0}}{m}$. (ii) The $y$-oriented currents can be explained as the currents that correspond to the TEM-wave that is excited inside the parallel-plate waveguide consisting of the PEC ground plate and the PEC metallization, filled with a dielectric. The wavelength of the TEM-wave then equals $\lambda_{TEM} = \lambda_0/\sqrt{\varepsilon_0} = 8.77$ mm. This wavelength nicely corresponds to the number of oscillations observed in the $y$-oriented current.

![Figure 4](image.png)

Fig. 4: $x$-oriented current density $J_x$ on the semi-infinite plate (perpendicular illumination).

In the next example, the same substrate and metallization are used, but the plane wave now impinges obliquely. The angles of incidence are chosen as follows: $\theta = 30^\circ$ and $\phi = 0^\circ$, and hence, the plane wave is defined as $E_{PW}(r) = (x + iy)e^{j\omega_0 z}, i.e. under perpendicular incidence ($\theta = 0^\circ$), and with an angular frequency of $\omega = 2\pi 10$ GHz. The current density on this PEC plate, induced by the plane wave, is computed using the technique described in Section II. The magnitude and the phase of the $x$- and the $y$-oriented current densities are shown in Figs. 7 and 8, and also in Fig. 9 where a cross-section is made along $x = (m + 1/2)b = 2.5$ mm. It is observed from Figs. 7 and 8 that there is no variation of the current density’s magnitude along the $x$-dimension, as expected. There is, however, a variation of its phase. This is clearly illustrated in Fig. 10, where the phase of the $x$- and the $y$-oriented current density is shown along the cross-section $y = 5\lambda_0 = 17.1 \lambda_1 = 150$ mm. This phase varies linearly between $x = 0$ and $x = b$ (from 0.57 rad to 1.09 rad for $J_x$, and from 0.97 rad to 1.49 rad for $J_y$). Using (3), it
is validated that this phase variation of 0.52 rad is in perfect agreement with the predicted value of 
\[ \psi = -b k_0 \sin \theta \cos \phi = -0.52. \]

The results obtained for this semi-infinite plate validate the proposed 1-D periodic BIE-MoM technique.

**B. Straight microstrip line**

As an important but simple application example, we consider a straight microstrip line residing on the same substrate as presented above in Section III-A. The metallization within the unit cell is also the one shown in Fig. 2, but now, the width is much smaller, i.e. \( w = 4.5 \) mm. Again, the plane wave \( \mathbf{E}^{PW}(r) = \left( \frac{\sqrt{2}}{2} \mathbf{x} + \frac{\sqrt{2}}{2} \mathbf{y} \right) e^{jk_0(\xi + \frac{5\pi}{4})} \) \( \forall \mathbf{r} \) with angular frequency \( \omega = 2\pi \times 10 \) GHz impinges upon the structure. Although the geometry is invariant w.r.t \( x \)-axis, the excitation exhibits a variation of the phase, and hence, this situation cannot be decomposed into a pure 2-D TM- and TE-problem (there is a coupling between the \( x \) - and \( y \)-oriented currents). For a period \( b = 10 \) mm, the magnitude of the \( x \) - and \( y \)-oriented current density along the cross-section \( x = b/2 = 5 \) mm is presented in Fig. 11. As explained above (Section III-
the same microstrip configuration, but now for ten different values of the period \( b \), i.e. for \( b \) varying from 10 mm to 1 mm in steps of 1 mm. Taking the result of Fig. 11, where \( b = b_{\text{ref}} = 10 \) mm, as a reference result, the relative error between the magnitude of the current densities is calculated as follows:

\[
\delta_x(b) = \frac{\int_0^w |J_{x}^{\text{ref}}(b_{\text{ref}}/2, y, d)| \, dy - \int_0^w |J_{x}^{\var}(b/2, y, d)| \, dy}{\int_0^w |J_{x}^{\text{ref}}(b_{\text{ref}}/2, y, d)| \, dy},
\]

\[
\delta_y(b) = \frac{\int_0^w |J_{y}^{\text{ref}}(b_{\text{ref}}/2, y, d)| \, dy - \int_0^w |J_{y}^{\var}(b/2, y, d)| \, dy}{\int_0^w |J_{y}^{\text{ref}}(b_{\text{ref}}/2, y, d)| \, dy}.
\]

where \( J_{x}^{\text{ref}}(b_{\text{ref}}/2, y, d) \) and \( J_{y}^{\text{ref}}(b_{\text{ref}}/2, y, d) \) are the reference results presented in Fig. 11, and with \( J_{x}^{\var}(b/2, y, d) \) and \( J_{y}^{\var}(b/2, y, d) \) the current densities obtained for the same microstrip configuration, but using another value for the period \( b \). The relative errors (14) and (15) are shown in Fig. 13. It is observed that reducing the period \( b \) yields the same result, at least, within a margin of error that is smaller than 0.01%. Hence, apart from using this result as a validation, it is also clear that for straight configurations, it is beneficial to take \( b \) small, as this reduces the number of unknowns \( N \) in the MoM. Note, however, that when the number of discretization cells along the \( x \)-direction becomes too small, say less than three, this methods breaks down. In the above case for \( b = 1 \) mm, there are four discretization cells along the \( x \)-direction.

### C. Serpentine delay line

The last application example, presented in this section, is the serpentine delay line configuration shown in Fig. 1. The PEC metallization within one unit cell, indicating all detailed dimensions, is shown in Fig. 14. This metallization resides on top of a PEC-backed, non-magnetic, lossy substrate of thickness \( d = 1.5 \) mm, relative permittivity \( \varepsilon_r = 4.3 \), and loss tangent \( \tan \delta = 0.02 \). A similar serpentine delay line was proposed in [10], where its signal integrity properties were studied. Here, we evaluate the effects of radiation onto the serpentine delay line at an angular frequency of \( \omega = 2\pi \times 20 \) GHz by letting a plane wave \( E^{\text{PW}}(r) = (x + y - \sqrt{2}z)e^{j[k(\frac{1}{\sqrt{2}}x + \frac{1}{\sqrt{2}}y + \frac{\sqrt{2}}{2}z)]} \) obliquely impinge upon it (\( \theta = 45^\circ \) and \( \phi = 45^\circ \)). The magnitude of the \( x \)- and \( y \)-oriented current...
and (11), as presented in Section II-C. Furthermore, it takes of periods depends on the convergence rate of the series (10) accuracy. The convergence rate as a function of the number of unit cells in the SVD-PML-MLFMA further increases the 1-D periodic BIE-MoM. Of course, increasing the number of unit cells is shown. There is an oriented induced current density that flows within the center unit cell (i.e. the fourth unit cell) is shown. There is an excellent agreement with the results obtained by the new 1-D periodic BIE-MoM, presented in this paper, is used. For comparison, a finite serpentine line consisting of seven unit cells and illuminated by the same plane wave, is simulated using the SVD-PML-MLFMA technique [18]. This technique was especially conceived to rapidly analyze large, but finite, non-periodic structures residing on microstrip substrates. In Figs. 15(b) and 16(b) the magnitude of the -oriented current density on the straight microstrip line for a varying period , compared to the situation with . This speed-up factor of 10.20 is significant and it is of course thanks to the fact that the number of unknowns in the periodic BIE-MoM scheme is rather small, as only one representative unit cell needs to be considered. More specifically, there were unknowns in the 1-D periodic BIE-MoM scheme and in the SVD-PML-MLFMA scheme.

As the analysis can be restricted to one single unit cell, the technique presented here allows a rapid evaluation of the distributed currents induced on (multiconductor) transmission lines, such as straight microstrip lines, coupled microstrip lines, serpentine delay lines, etc. The results can be used for further analysis purposes. Using the Baum-Liu-Tesche (BLT) equation, which was first introduced in [30], for describing transmission lines, the voltages and currents at loads connected to the lines can be estimated. Also, conjunction with advanced EMI analysis techniques for plane wave excitation [31], or even for near-zone illumination [32], can be investigated. The (application) examples given above validate the presented technique but represent idealized scenarios, of interest to the EMC/EMI community.

IV. CONCLUSIONS

An MPIE is constructed to model the current density induced on 1-D periodic metallizations residing on a microstrip...
The periodic structure can be analyzed by merely considering one single representative unit cell, this in accordance with the Floquet-Bloch theorem. Thereto, the pertinent 1-D periodic layered medium Green’s functions have to be used. Here, we obtain these Green’s function in closed form upon it, is accurately simulated and compared to the previously developed (and validated) SVD-PML-MLFMA, showing excellent agreement. Although this SVD-PML-MLFMA was especially constructed to rapidly assess the radiation onto large but finite microstrip structures, the 1-D periodic BIE-MoM is still faster, as only a single unit cell needs to be considered.

The theory is illustrated by simulating the induced current density onto three different metallizations, illuminated by plane waves, and residing on microstrip substrates. First, the radiation onto a semi-infinite PEC plate is considered. For a perpendicular incidence of the plane wave, it is demonstrable that this situation can be decomposed into a pure 2-D TM- and TE-problem, and the results obtained with the new 1-D periodic BIE-MoM are compared with results from literature. For oblique illumination, it is demonstrated that the phase of the current density varies linearly within the unit cell, as a continuous current flow across these borders should be guaranteed without destroying the periodicity.

The theory is illustrated by simulating the induced current density onto three different metallizations, illuminated by plane waves, and residing on microstrip substrates. First, the radiation onto a semi-infinite PEC plate is considered. For a perpendicular incidence of the plane wave, it is demonstrable that this situation can be decomposed into a pure 2-D TM- and TE-problem, and the results obtained with the new 1-D periodic BIE-MoM are compared with results from literature. For oblique illumination, it is demonstrated that the phase of the current density varies linearly within the unit cell, as expected from the Floquet-Bloch theorem. Second, the current density varies linearly within the unit cell, this in accordance with the Floquet-Bloch theorem. Thereto, the pertinent 1-D periodic layered medium Green’s functions have to be used. Here, we obtain these Green’s function in closed form upon it, is accurately simulated and compared to the previously developed (and validated) SVD-PML-MLFMA, showing excellent agreement. Although this SVD-PML-MLFMA was especially constructed to rapidly assess the radiation onto large but finite microstrip structures, the 1-D periodic BIE-MoM is still faster, as only a single unit cell needs to be considered.


